9-bit D-type flip-flop with 5 V tolerant inputs/outputs; positive edge-trigger; 3-state Rev. 2 — 1 May 2019 Product of

Product data sheet

1. General description

The 74LVC823A-Q100 is a 9-bit D-type flip-flop with common clock (pin CP), clock enable (pin \overline{CE}), master reset (pin \overline{MR}) and 3-state outputs (pins Qn) for bus-oriented applications. The 9 flip-flops stores the state of their individual D-inputs that meet the set-up and hold times requirements on the LOW to HIGH CP transition, provided pin \overline{CE} is LOW. When pin \overline{CE} is HIGH, the flip-flops hold their data. A LOW on pin \overline{MR} resets all flip-flops. When pin \overline{OE} is LOW, the contents of the 9 flip-flops are available at the outputs. When pin \overline{OE} is HIGH, the outputs go to the high-impedance OFF-state. Operation of the \overline{OE} input does not affect the state of the flip-flops.

Inputs can be driven from either 3.3 V or 5 V devices. When disabled, up to 5.5 V can be applied to the outputs. These features allow the use of these devices as translators in mixed 3.3 V and 5 V applications.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- 5 V tolerant inputs/outputs for interfacing with 5 V logic
- Wide supply voltage range from 1.2 V to 3.6 V
- CMOS low power consumption
- Direct interface with TTL levels
- Flow-through pinout architecture
- 9-bit positive edge-triggered register
- Independent register and 3-state buffer operation
- Complies with JEDEC standard:
 - JESD8-7A (1.65 V to 1.95 V)
 - JESD8-5A (2.3 V to 2.7 V)
 - JESD8-C/JESD36 (2.7 V to 3.6 V)
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

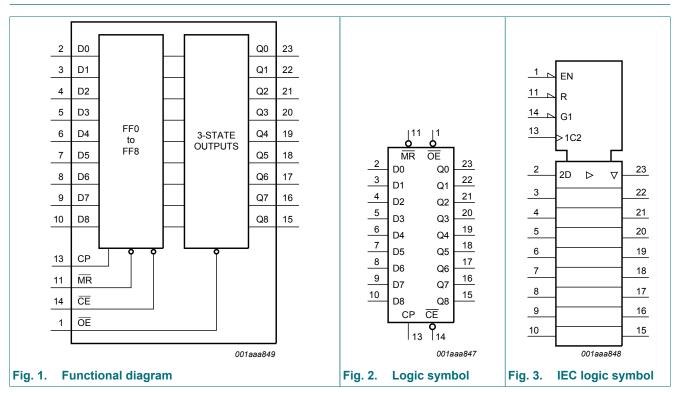
3. Ordering information

Table 1. Ordering information

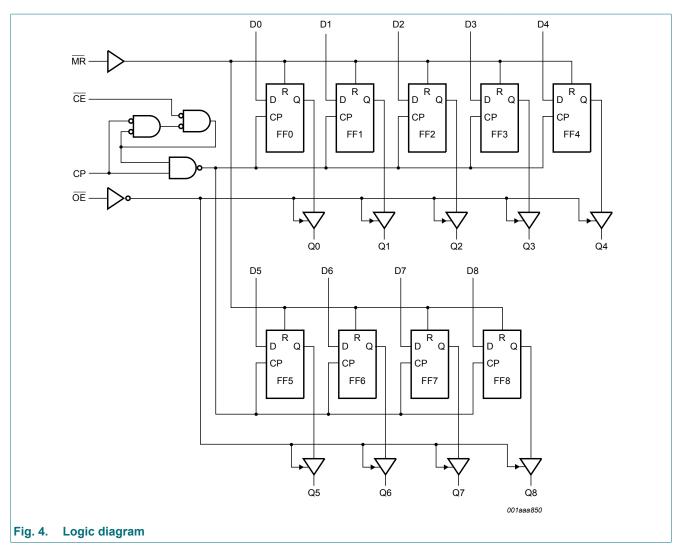
Type number	Package								
	Temperature range	Name	Description	Version					
74LVC823ABQ-Q100	-40 °C to +125 °C	DHVQFN24	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 24 terminals; body 3.5 × 5.5 × 0.85 mm	SOT815-1					

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4. Functional diagram



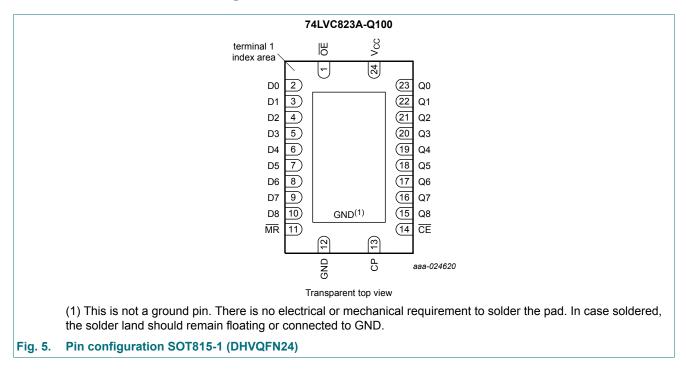
9-bit D-type flip-flop with 5 V tolerant inputs/outputs; positive edge-trigger; 3-state



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5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description		
Pin	Name	Description
ŌĒ	1	output enable input (active LOW)
MR	11	master reset input (active LOW)
D0, D1, D2, D3, D4, D5, D6, D7, D8	2, 3, 4, 5, 6, 7, 8, 9, 10	data input
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7, Q8	23, 22, 21, 20, 19, 18, 17, 16, 15	3-state flip-flop output
СР	13	clock input (LOW to HIGH; edge-triggered)
CE	14	clock enable input (active LOW)
GND	12	ground (0 V)
V _{CC}	24	supply voltage

6. Functional description

Table 3. Function table

H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the LOW to HIGH CP transition

L = LOW voltage level; I = LOW voltage level one set-up time prior to the LOW to HIGH CP transition

↑ = LOW to HIGH level transition

Z = high-impedance OFF-state; X = don't care; NC = no change

Operating mode	Input					Internal	Output
	ŌE	MR	CE	СР	Dn	flip-flop	Qn
Clear	L	L	Х	Х	Х	L	L
Load and read register	L	Н	L	1	I	L	L
	L	Н	L	1	h	Н	Н
Load register and	Н	Н	L	1	I	L	Z
disable outputs	Н	Н	L	1	h	Н	Z
Hold	L	Н	Н	NC	Х	NC	NC

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+6.5	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+6.5	V
I _{OK}	output clamping current	$V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0 V	-	±50	mA
Vo	output voltage	HIGH or LOW state [2]	-0.5	V _{CC} + 0.5	V
		3-state [2]	-0.5	+6.5	V
I _O	output current	$V_{O} = 0 V \text{ to } V_{CC}$	-	±50	mA
I _{CC}	supply current		-	100	mA
I _{GND}	ground current		-100	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C [3]	-	500	mW

[1] The minimum input voltage ratings may be exceeded if the input current ratings are observed.

[2] The output voltage ratings may be exceeded if the output current ratings are observed.

[3] For DHVQFN24 packages: P_{tot} derates linearly with 4.5 mW/K above 60 °C.

8. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		1.65	-	3.6	V
		functional	1.2	-	-	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	HIGH or LOW state	0	-	V _{CC}	V
		3-state	0	-	5.5	V
T _{amb}	ambient temperature	in free air	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 1.65 V to 2.7 V	0	-	20	ns/V
		V _{CC} = 2.7 V to 3.6 V	0	-	10	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +85	°C	-40 °C to	+125 °C	Unit
			Min	Тур <mark>[1]</mark>	Max	Min	Мах	
V _{IH}	HIGH-level	V _{CC} = 1.2 V	1.08	-	-	1.08	-	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	0.65V _{CC}	-	-	0.65V _{CC}	-	V
		V _{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
V _{IL}	LOW-level input	V _{CC} = 1.2 V	-	-	0.12	-	0.12	V
	voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.35V _{CC}	-	0.35V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}						
	output voltage	I _O = -100 μA; V _{CC} = 1.65 V to 3.6 V	V _{CC} - 0.2	-	-	V _{CC} - 0.3	-	V
		I _O = -4 mA; V _{CC} = 1.65 V	1.2	-	-	1.05	-	V
		I _O = -8 mA; V _{CC} = 2.3 V	1.8	-	-	1.65	-	V
		I _O = -12 mA; V _{CC} = 2.7 V	2.2	-	-	2.05	-	V
		I _O = -18 mA; V _{CC} = 3.0 V	2.4	-	-	2.25	-	V
		I _O = -24 mA; V _{CC} = 3.0 V	2.2	-	-	2.0	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	output voltage	I _O = 100 μA; V _{CC} = 1.65 V to 3.6 V	-	-	0.2	-	0.3	V
		I _O = 4 mA; V _{CC} = 1.65 V	-	-	0.45	-	0.65	V
		I _O = 8 mA; V _{CC} = 2.3 V	-	-	0.6	-	0.8	V
		I _O = 12 mA; V _{CC} = 2.7 V	-	-	0.4	-	0.6	V
		I _O = 24 mA; V _{CC} = 3.0 V	-	-	0.55	-	0.8	V
l _l	input leakage current	V _{CC} = 3.6 V; V _I = 5.5 V or GND	-	±0.1	±5	-	±20	μA
I _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_{CC} = 3.6 \text{ V};$ $V_O = 5.5 \text{ V or GND}$	-	0.1	±5	-	±20	μA

9-bit D-type flip-flop with 5 V tolerant inputs/outputs; positive edge-trigger; 3-state

Symbol	Parameter	Conditions	-4() °C to +85	°C	-40 °C to	o +125 °C	Unit
			Min	Typ [1]	Max	Min	Max]
I _{OFF}	power-off leakage current	$V_{CC} = 0 V; V_{I} \text{ or } V_{O} = 5.5 V$	-	0.1	±10	-	±20	μA
I _{CC}	supply current	V_{CC} = 3.6 V; V_{I} = V_{CC} or GND; I_{O} = 0 A	-	0.1	10	-	40	μA
ΔI _{CC}	additional supply current	per input pin; V_{CC} = 2.7 V to 3.6 V; V _I = V _{CC} - 0.6 V; I _O = 0 A	-	5	500	-	5000	μA
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V ₁ = GND to V _{CC}	-	5.0	-	-	-	pF

[1] All typical values are measured at V_{CC} = 3.3 V (unless stated otherwise) and T_{amb} = 25 °C.

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Fig. 10.

Symbol	Parameter	Conditions		-40	°C to +85	°C	-40 °C to	o +125 ℃	Unit
				Min	Тур [1]	Мах	Min	Max	
t _{pd}	propagation	CP to Qn; see Fig. 6	2]						
	delay	V _{CC} = 1.2 V		-	20	-	-	-	ns
		V _{CC} = 1.65 V to 1.95 V		2.4	8.4	18.7	2.4	21.5	ns
		V _{CC} = 2.3 V to 2.7 V		1.7	4.4	9.6	1.7	11.1	ns
		V _{CC} = 2.7 V		1.5	4.1	8.9	1.5	11.5	ns
		V _{CC} = 3.0 V to 3.6 V		1.5	3.7	8.0	1.5	10.0	ns
t _{PHL}	HIGH to LOW	MR to Qn; see Fig. 8							
	propagation delay	V _{CC} = 1.2 V		-	15	-	-	-	ns
		V _{CC} = 1.65 V to 1.95 V		2.1	9.5	21.4	2.1	24.7	ns
		V _{CC} = 2.3 V to 2.7 V		1.5	4.9	10.5	1.5	12.1	ns
		V _{CC} = 2.7 V		1.5	4.7	8.8	1.5	11.0	ns
		V _{CC} = 3.0 V to 3.6 V		1.5	4.1	7.9	1.5	10.0	ns
t _{en}	enable time	OE to Qn; see Fig. 9	2]						
		V _{CC} = 1.2 V		-	18	-	-	-	ns
		V _{CC} = 1.65 V to 1.95 V		1.7	7.4	16.5	1.7	19.0	ns
		V _{CC} = 2.3 V to 2.7 V		1.5	4.2	9.1	1.5	10.5	ns
		V _{CC} = 2.7 V		1.5	4.3	8.3	1.5	10.5	ns
		V _{CC} = 3.0 V to 3.6 V		1.5	3.4	7.2	1.5	9.0	ns
t _{dis}	disable time	OE to Qn; see Fig. 9 [2	2]						
		V _{CC} = 1.2 V		-	8.0	-	-	-	ns
		V _{CC} = 1.65 V to 1.95 V		2.3	4.2	10.0	2.3	11.5	ns
		V _{CC} = 2.3 V to 2.7 V		1.0	2.3	5.6	1.0	6.5	ns
		V _{CC} = 2.7 V		1.5	3.2	7.1	1.5	9.0	ns
		V _{CC} = 3.0 V to 3.6 V		1.5	2.9	6.0	1.5	7.5	ns

Symbol	Parameter	Conditions	-40) °C to +85	°C	-40 °C to	Unit	
			Min	Тур [1]	Мах	Min	Max	
t _W	pulse width	CP HIGH or LOW; see Fig. 6						
		V _{CC} = 1.65 V to 1.95 V	5.0	-	-	5.0	-	ns
		V _{CC} = 2.3 V to 2.7 V	4.0	-	-	4.0	-	ns
		V _{CC} = 2.7 V	3.3	-	-	3.3	-	ns
		V _{CC} = 3.0 V to 3.6 V	3.3	1.7	-	3.3	-	ns
		MR HIGH or LOW; see Fig. 8						
		V _{CC} = 1.65 V to 1.95 V	5.0	-	-	5.0	-	ns
		V _{CC} = 2.3 V to 2.7 V	4.0	-	-	4.0	-	ns
		V _{CC} = 2.7 V	3.3	-	-	3.3	-	ns
		V _{CC} = 3.0 V to 3.6 V	3.3	1.7	-	3.3	-	ns
t _{su}	set-up time	Dn to CP; see Fig. 7						
04		V _{CC} = 1.65 V to 1.95 V	3.0	-	-	3.0	-	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	-	-	2.0	-	ns
		V _{CC} = 2.7 V	1.0	-	-	1.0	-	ns
		V _{CC} = 3.0 V to 3.6 V	+1.8	-0.8	-	+1.8	-	ns
		CE to CP; see Fig. 7						
		V _{CC} = 1.65 V to 1.95 V	3.0	-	-	3.0	-	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	-	-	2.0	-	ns
		V _{CC} = 2.7 V	1.8	_	_	1.8	_	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	0.0	-	1.3	-	ns
t _{rec}	recovery time	MR; see Fig. 8				-		
100	,,	V _{CC} = 1.65 V to 1.95 V	3.0	-	_	3.0	_	ns
		V _{CC} = 2.3 V to 2.7 V	2.5	_	_	2.5	_	ns
		V _{CC} = 2.7 V	2.0	-	_	2.0	_	ns
		V _{CC} = 3.0 V to 3.6 V	+1.0	-0.5		+1.0	_	ns
t _h	hold time	Dn to CP; see Fig. 7						
-11		$V_{CC} = 1.65 V \text{ to } 1.95 V$	3.0	_	_	3.0	_	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.5	_	_	2.5	_	ns
		$V_{\rm CC} = 2.7 \text{V}$	2.0	-	-	2.0	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.0	0.8	_	2.0	_	ns
		CE to CP; see Fig. 7						
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	3.0	_	_	3.0	_	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.0	_		2.0	_	ns
		$V_{\rm CC} = 2.7 \text{V}$	1.3	_	-	1.3	_	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.3	0.0	-	1.3	_	ns
f _{max}	maximum	CP; see Fig. 6		0.0				
'IIIdX	frequency	$V_{\rm CC} = 1.65 \text{ V to } 1.95 \text{ V}$	100	_		80	_	MHz
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	125	_		100	_	MHz
		$V_{CC} = 2.7 V$	150	-		120	_	MHz
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	150	200	-	120	_	MHz
t _{sk(o)}	output skew time	$Q_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ [3]	-	-	1.0	-	1.5	ns

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9-bit D-type flip-flop with 5 V tolerant inputs/outputs; positive edge-trigger; 3-state

Symbol	Parameter	Conditions		-40 °C to +85 °C			-40 °C to	Unit	
				Min	Тур [1]	Мах	Min	Мах	
C _{PD}	power	per input; V_I = GND to V_{CC}	[4]						
	dissipation capacitance	V _{CC} = 1.65 V to 1.95 V		-	12.4	-	-	-	pF
	capacitance	V _{CC} = 2.3 V to 2.7 V		-	14.5	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V		-	16.4	-	-	-	pF

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.2 V, 1.8 V, 2.5 V, 2.7 V and 3.3 V respectively.

 $\label{eq:pd} \ensuremath{\left[2\right]} \quad t_{pd} \mbox{ is the same as } t_{PLH} \mbox{ and } t_{PHL}.$

 t_{en} is the same as t_{PZL} and $t_{PZH}.$

 t_{dis} is the same as t_{PLZ} and $t_{\text{PHZ}}.$

[3] Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz; f_o = output frequency in MHz

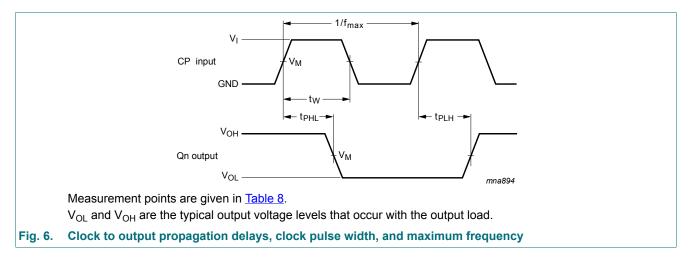
 C_L = output load capacitance in pF

V_{CC} = supply voltage in Volts

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs

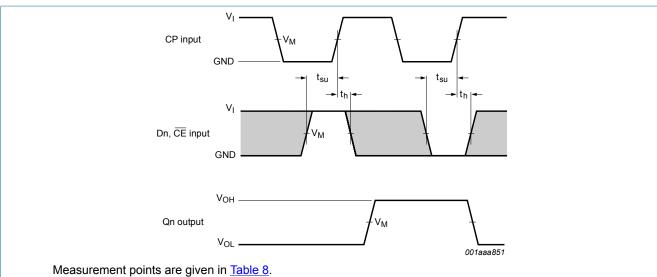
10.1. Waveforms and test circuit



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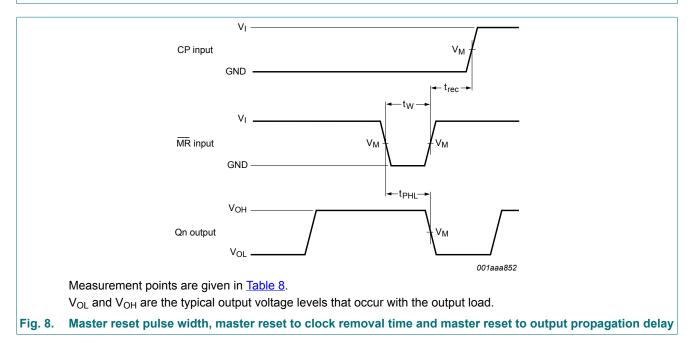
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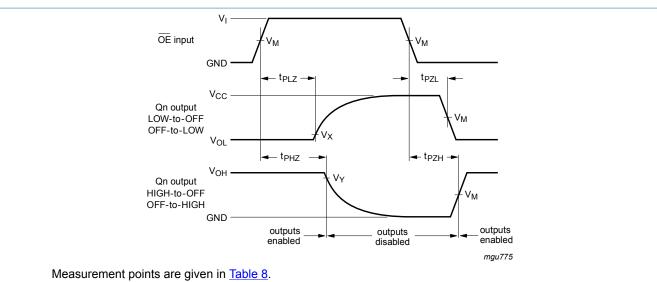


V_{OL} and V_{OH} are the typical output voltage levels that occur with the output load. The shaded areas indicate when the input is permitted to change for predicable output performance.

Data set-up and hold times for data and clock enable inputs to clock input Fig. 7.



9-bit D-type flip-flop with 5 V tolerant inputs/outputs; positive edge-trigger; 3-state



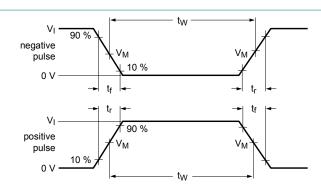
 V_{OL} and V_{OH} are the typical output voltage drops that occur with the output load.

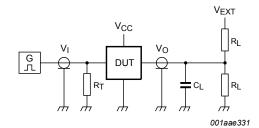
Fig. 9. 3-state outputs enable and disable times

Table 8. Measurement points

Supply voltage	Input		Output	Output				
V _{cc}	VI	V _M	V _M	V _X	VY			
1.2 V	V _{CC}	0.5 × V _{CC}	0.5 × V _{CC}	V _{OL} + 0.15 V	V _{OH} - 0.15 V			
1.65 V to 1.95 V	V _{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V _{OL} + 0.15 V	V _{OH} - 0.15 V			
2.3 V to 2.7 V	V _{CC}	$0.5 \times V_{CC}$	0.5 × V _{CC}	V _{OL} + 0.15 V	V _{OH} - 0.15 V			
2.7 V	2.7 V	1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} - 0.3 V			
3.0 V to 3.6 V	2.7 V	1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} - 0.3 V			

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Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig. 10. Test circuit for measuring switching times

Table 9. Test data

Supply voltage	Input		Load	Load		V _{EXT}		
	VI	t _r , t _f	CL	RL	t _{PLH} , t _{PHL}	t _{PLZ} , t _{PZL}	t _{PHZ} , t _{PZH}	
1.2 V	V _{CC}	≤ 2 ns	30 pF	1 kΩ	open	$2 \times V_{CC}$	GND	
1.65 V to 1.95 V	V _{CC}	≤ 2 ns	30 pF	1 kΩ	open	$2 \times V_{CC}$	GND	
2.3 V to 2.7 V	V _{CC}	≤ 2 ns	30 pF	500 Ω	open	$2 \times V_{CC}$	GND	
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	2 × V _{CC}	GND	
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	$2 \times V_{CC}$	GND	

11. Package outline

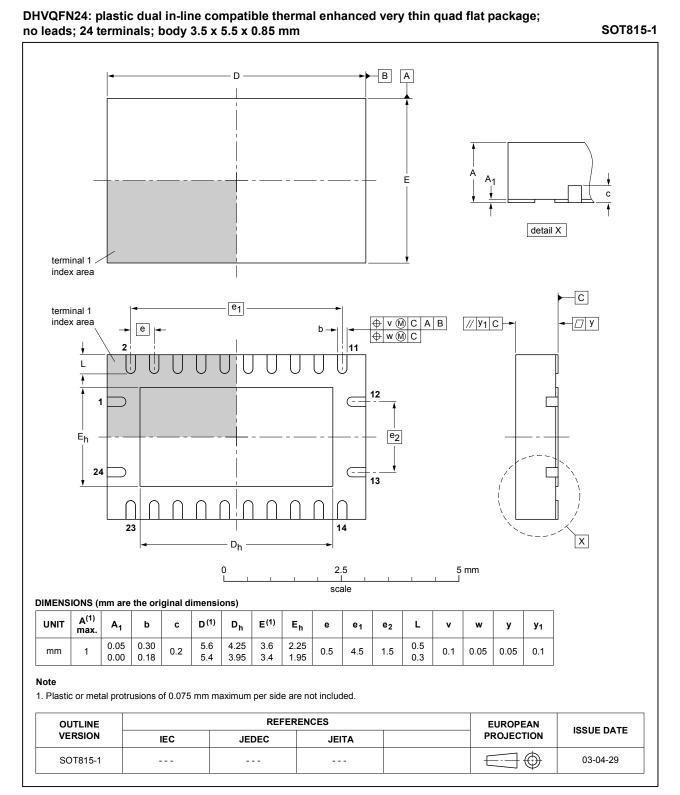


Fig. 11. Package outline SOT815-1 (DHVQFN24)

74LVC823A_Q100

12. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74LVC823A_Q100 v.2	20190501	Product data sheet	-	74LVC823A_Q100 v.1	
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. 				
74LVC823A_Q100 v.1	20160915	Product data sheet	-	-	

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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